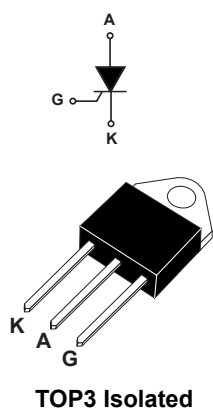


60 A, 1200 V standard SCR



Features

- Max. Repetitive Blocking Voltage = V_{DRM} , V_{RRM} = 1200 V
- I_{GT} maximum = 50 mA
- High static and dynamic commutation:
 - di/dt = 100 A/ μ s
 - dV/dt = 2000 V/ μ s
- ECOPACK®2 component (RoHS and HF compliance)
- Complies with UL 1557 standard (File ref : E81734)

Applications

- Solar / Wind renewable energy inverters and rectifiers
- Solid state relay (SSR)
- Uninterruptible power supply (UPS)
- Industrial SMPS
- Bypass
- AC DC inrush current limiter (ICL)
- Battery charger
- AC DC voltage controlled rectifier
- Industrial welding systems
- Off board automotive battery charger
- Soft starter
- Heating systems

Description

The TN6050-12PI SCR is suitable in industrial applications where high immunity is required with a lower gate current and ceramic isolated tab, UL1557 certified rated at 2.5 kV RMS and UL94-V0 resin compliance.

Available in through-hole high power package TOP3 isolated tab.

Product status	
TN6050-12PI	
Product summary	
Order code	TN6050-12PI
Package	TOP3 isolated
$I_{T(RMS)}$	60 A
V_{DRM}/V_{RRM}	1200 V
I_{GT}	50 mA

1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter		Value	Unit	
I _{T(RMS)}	On-state RMS current (180 ° conduction angle)	T _c = 82.2 °C	60	A	
I _{T(AV)}	Average on-state current (180 ° conduction angle)		38		
I _{TSM}	Non repetitive surge peak on-state current (T _j initial = 25 °C)	t _p = 8.3 ms	763	A	
		t _p = 10 ms	700		
I ² t	I ² t value for fusing	t _p = 10 ms	2450	A ² s	
dI/dt	Critical rate of rise of on-state current I _G = 100 mA, dI _G /dt = 1 A/μs	T _j = 25 °C	100	A/μs	
I _{GM}	Maximum peak positive gate current	t _p = 20 μs	T _j = 125 °C	8	A
V _{GM}	Maximum peak positive gate voltage			5	V
P _{G(AV)}	Average gate power dissipation		T _j = 125 °C	1	W
V _{RGM}	Maximum peak reverse gate voltage			3.5	V
T _{stg}	Storage junction temperature range			-40 to +150	°C
T _j	Operating junction temperature range			-40 to +125	

Table 2. Electrical characteristics ($T_j = 25\text{ °C}$ unless otherwise specified)

Symbol	Test conditions			Value	Unit
I _{GT}	V _D = 12 V, R _L = 33 Ω		Min.	8	mA
Max.			50		
V _{GT}			Max.	1.3	V
V _{GD}	V _D = V _{DRM} , R _L = 3.3 kΩ	T _j = 125 °C	Min.	0.2	V
I _H	I _T = 500 mA, gate open		Max.	100	mA
I _L	I _G = 1.2 x I _{GT}		Max.	130	mA
dV/dt	V _D = 67% V _{DRM} , gate open	T _j = 125 °C	Min.	2000	V/μs
t _{gt}	I _T = 50 A, V _D = V _{DRM} , I _G = 200 mA, (dI _G /dt) max = 0.2 A/μs		Typ.	2	μs
t _q	I _{TM} = 50 A, V _D = 800 V, dI _{TM} /dt = 30 A/μs, V _R = 75 V, dV _D /dt = 20 V/μs	T _j = 125 °C	Typ.	100	μs

Table 3. Static characteristics

Symbol	Test conditions			Value	Unit
V _{TM}	I _{TM} = 120 A, t _p = 380 μs	T _J = 25 °C	Max.	1.75	V
V _{TO}	Threshold voltage	T _J = 125 °C	Max.	0.93	
R _D	Dynamic resistance	T _J = 125 °C	Max.	7.1	mΩ
I _{DRM} , I _{RRM}	V _{DRM} = V _{RRM} = 1200 V	T _J = 25 °C	Max.	10	μA
		T _J = 125 °C		6.5	mA

Table 4. Thermal parameters

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case (DC)	Typ.	0.70	°C/W
$R_{th(j-a)}$	Junction to ambient (DC)		50	

1.1 Characteristics curves

Figure 1. Maximum average power dissipation versus average on-state current

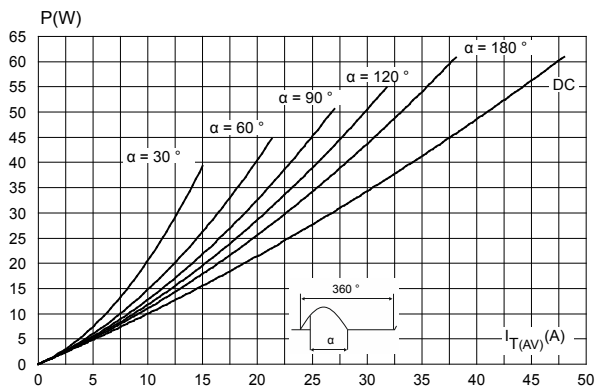


Figure 2. Average and DC on-state current versus case temperature

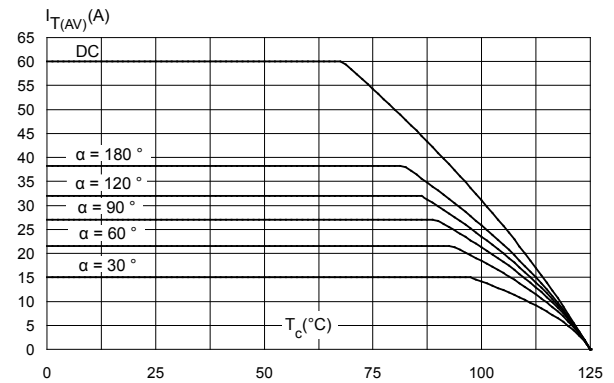


Figure 3. On-state characteristics (maximum values)

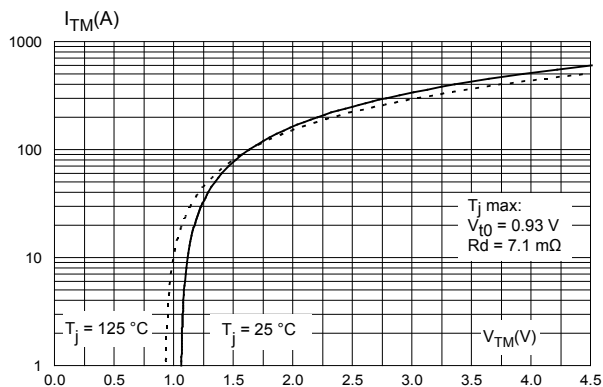


Figure 4. Average and D.C. on-state current versus ambient temperature

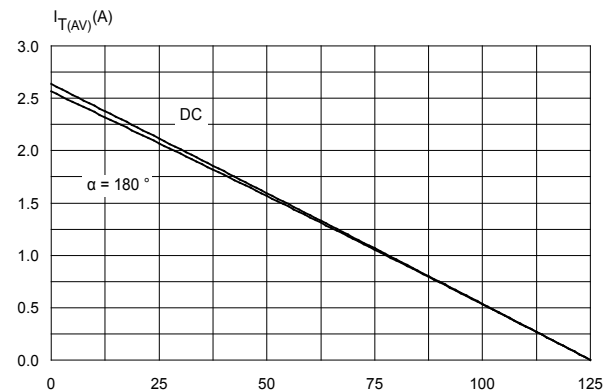


Figure 5. Relative variation of thermal impedance junction to case and junction to ambient versus pulse duration

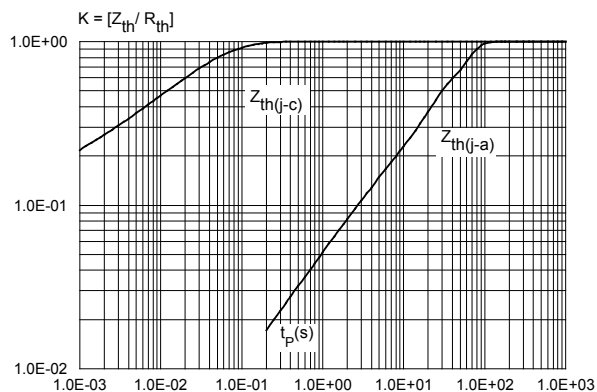


Figure 6. Surge peak on-state current versus number of cycles

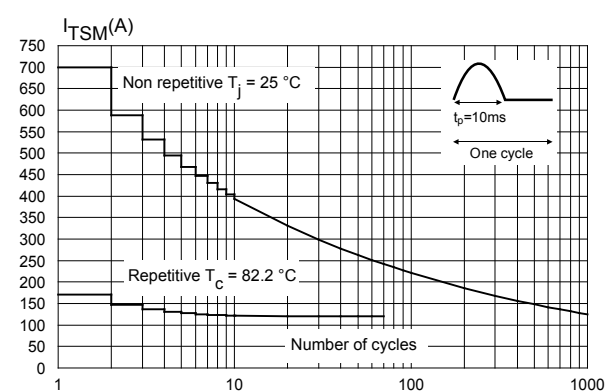


Figure 7. Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms

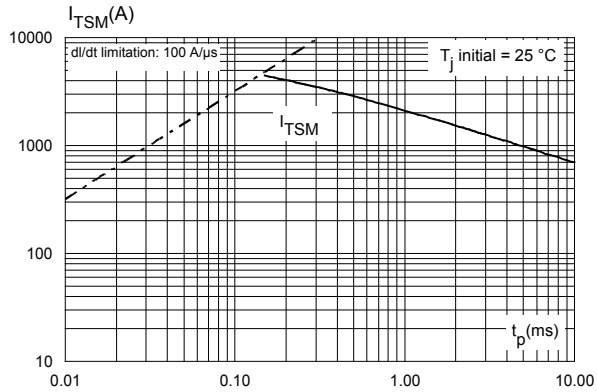


Figure 8. Relative variation of gate trigger current and gate trigger voltage versus junction temperature (typical value)

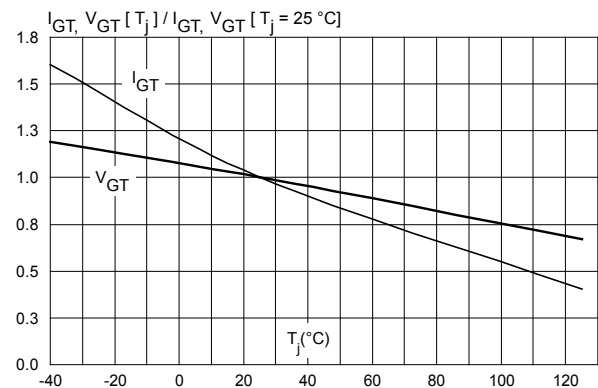


Figure 9. Relative variation of holding and latching current versus junction temperature (typical value)

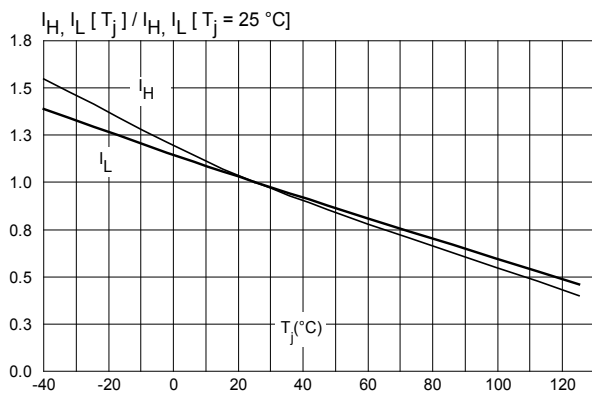


Figure 10. Relative variation of static dV/dt immunity versus junction temperature

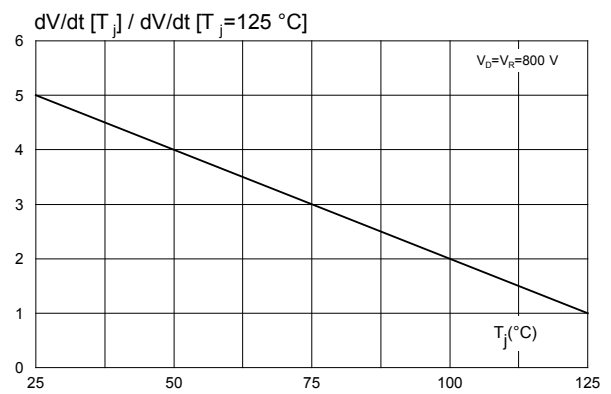
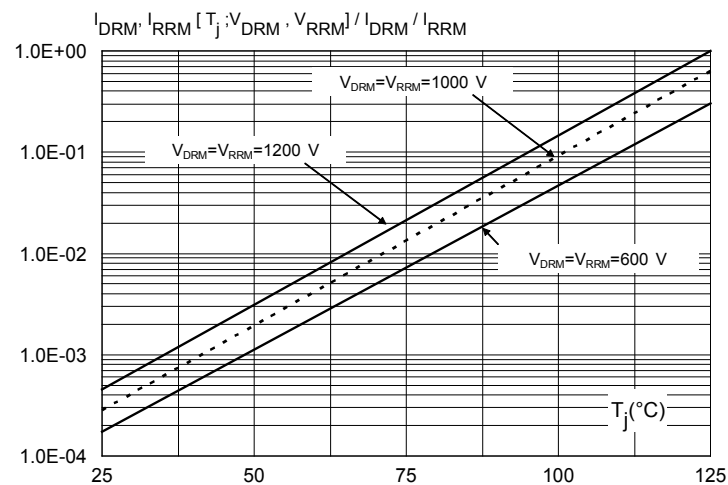


Figure 11. Relative variation of leakage current versus junction temperature for different values of blocking voltage (typical values)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK®** packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 TOP3 Isolated package information

- **ECOPACK®** (Lead-free plating and Halogen free package compliance)
- Lead-free package leads finishing
- Halogen-free molding compound resin meets UL94 standard level V0
- Recommended torque: 1.05 N·m (max. torque: 1.2 N·m)

Figure 12. TOP3 Isolated package outline

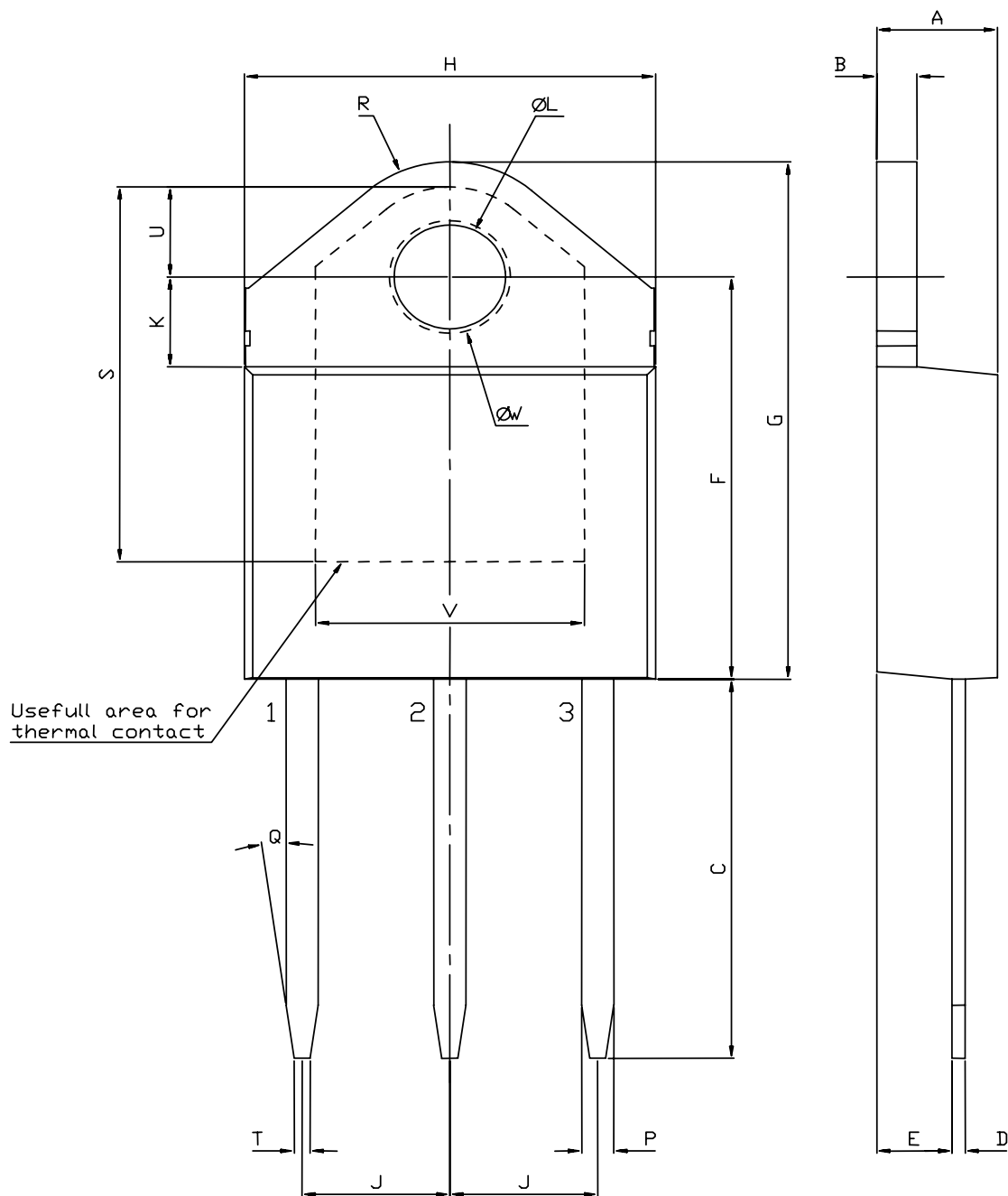


Table 5. TOP3 Isolated mechanical data

Ref.	Dimensions					
	mm			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.1732		0.1811
B	1.45		1.55	0.0571		0.0610
C	14.35		15.60	0.5650		0.6142
D	0.50		0.70	0.0197		0.0276
E	2.70		2.90	0.1063		0.1142
F	15.80		16.50	0.6220		0.6496
G	20.40		21.10	0.8031		0.8307
H	15.10		15.50	0.5945		0.6102
J	5.40		5.65	0.2126		0.2224
K	3.40		3.65	0.1339		0.1437
L	4.08		4.17	0.1606		0.1642
M	1.20		1.40	0.0472		0.0551
R		4.60			0.1811	

1. Inches given for reference only

3 Ordering information

Figure 13. Ordering information scheme

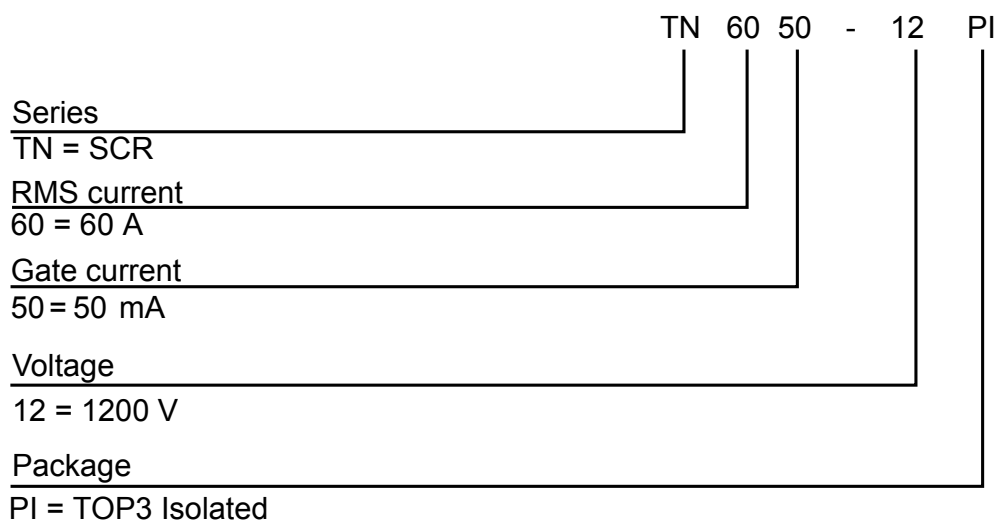


Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TN6050-12PI	TN605012PI	TOP3 Isolated	4.48 g	30	Tube

Revision history

Table 7. Document revision history

Date	Revision	Changes
14-Dec-2018	1	Initial release.

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